Power LDMOS transistor Rev. 2 — 1 September 2015

#### **Product profile** 1.

#### 1.1 General description

A 250 W extremely rugged LDMOS power transistor for broadcast and industrial applications in the HF to 600 MHz band.

#### Table 1. **Application information**

	Test signal	f	V <sub>DS</sub>	PL	G <sub>p</sub>	η <sub>D</sub>
		(MHz)	(V)	(W)	(dB)	(%)
Ī	pulsed RF	108	50	250	28	72

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### 1.2 Features and benefits

- Easy power control
- Integrated ESD protection
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (HF to 600 MHz)
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

### 1.3 Applications

- Industrial, scientific and medical applications
- Broadcast transmitter applications

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## 2. Pinning information

Table 2.	Pinning		
Pin	Description	Simplified outline	Graphic symbol
BLF182X	(R (SOT1121A)	·	
1	drain1		
2	drain2	1 2	
3	gate1		
4	gate2		3
5	source		
			۲
			2 sym117
BLF182X	(RS (SOT1121B)		
1	drain1	~~~~	
2	drain2		1
3	gate1		
4	gate2	3 4 5	3
5	source	[1]	
			l IF-1
			2 sym117

[1] Connected to flange.

### 3. Ordering information

#### Table 3. Ordering information

Type number Package				
Name Description			Version	
BLF182XR	-	flanged LDMOST ceramic package; 2 mounting holes; 4 leads	SOT1121A	
BLF182XRS	-	earless flanged ceramic package; 4 leads	SOT1121B	

### 4. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>DS</sub>	drain-source voltage		-	135	V
V <sub>GS</sub>	gate-source voltage		-6	+11	V
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature	[1]	-	225	°C

[1] Continuous use at maximum temperature will affect the reliability, for details refer to the on-line MTF calculator.

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## 5. Thermal characteristics

Table 5.   Thermal characteristics						
Symbol	Parameter	Conditions		Тур	Unit	
R <sub>th(j-c)</sub>	thermal resistance from junction to case	T <sub>j</sub> = 115 °C	[1][2]	<tbd></tbd>	K/W	
Z <sub>th(j-c)</sub>	transient thermal impedance from junction to case	$T_j$ = 150 °C; $t_p$ = 100 µs; $\delta$ = 20 %	<u>[3]</u>	<tbd></tbd>	K/W	

[1]  $T_j$  is the junction temperature.

[3] See <tbd>.

## 6. Characteristics

#### Table 6. DC characteristics

 $T_i = 25 \ ^{\circ}C$ ; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	V <sub>GS</sub> = 0 V; I <sub>D</sub> = 1.0 mA	135	-	-	V
V <sub>GS(th)</sub>	gate-source threshold voltage	V <sub>DS</sub> = 10 V; I <sub>D</sub> = 100 mA	1.25	1.8	2.25	V
V <sub>GSq</sub>	gate-source quiescent voltage	V <sub>DS</sub> = 50 V; I <sub>D</sub> = 50 mA	-	1.6	-	V
I <sub>DSS</sub>	drain leakage current	V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 50 V	-	-	1.4	μA
I <sub>DSX</sub>	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	14.3	-	A
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 11 V; V <sub>DS</sub> = 0 V	-	-	140	nA
R <sub>DS(on)</sub>	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 V;$ I <sub>D</sub> = 3.5 A	-	0.43	-	Ω

#### Table 7. AC characteristics

 $T_j = 25 \ ^{\circ}C$ ; per section unless otherwise specified.

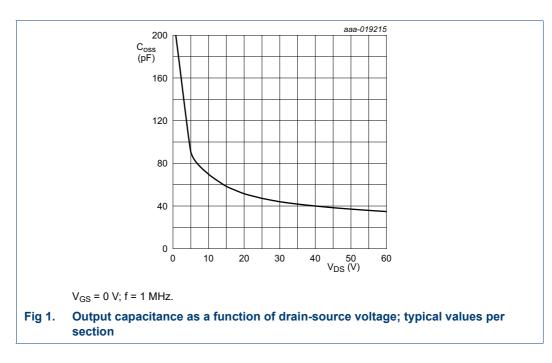
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
C <sub>rs</sub>	feedback capacitance	V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 50 V; f = 1 MHz	-	0.7	-	pF
C <sub>iss</sub>	input capacitance	V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 50 V; f = 1 MHz	-	116	-	pF
C <sub>oss</sub>	output capacitance	V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 50 V; f = 1 MHz	-	37	-	pF

#### Table 8. RF characteristics

Test signal: pulsed RF;  $t_p = 100 \ \mu$ s;  $\delta = 20 \ \%$ ;  $f = 108 \ MHz$ ; RF performance at  $V_{DS} = 50 \ V$ ;  $I_{Dq} = 100 \ mA$ ;  $T_{case} = 25 \ \%$ ; unless otherwise specified; in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
G <sub>p</sub>	power gain	P <sub>L</sub> = 250 W	<tbd></tbd>	28	-	dB
RL <sub>in</sub>	input return loss	P <sub>L</sub> = 250 W	-	-10	-	dB
η <sub>D</sub>	drain efficiency	P <sub>L</sub> = 250 W	<tbd></tbd>	72	-	%

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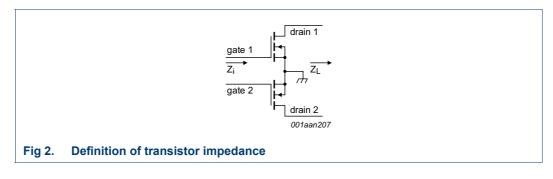


### 7. Test information

### 7.1 Ruggedness in class-AB operation

The BLF182XR and BLF182XRS are capable of withstanding a load mismatch corresponding to VSWR > 65 : 1 through all phases under the following conditions:  $V_{DS}$  = 50 V;  $I_{Dq}$  = 100 mA;  $P_L$  = 250 W pulsed; f = 108 MHz.

### 7.2 Impedance information



#### Table 9. Typical push-pull impedance

Simulated  $Z_i$  and  $Z_L$  device impedance; impedance info at  $V_{DS} = 50$  V and  $P_L = 250$  W.

f	Z <sub>i</sub>	ZL
(MHz)	(Ω)	(Ω)
108	<tbd></tbd>	<tbd></tbd>

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### 7.3 UIS avalanche energy

#### Table 10. Typical avalanche data per section

 $T_{amb} = 25 \, ^{\circ}C$ ; typical test data; test jig without water cooling.

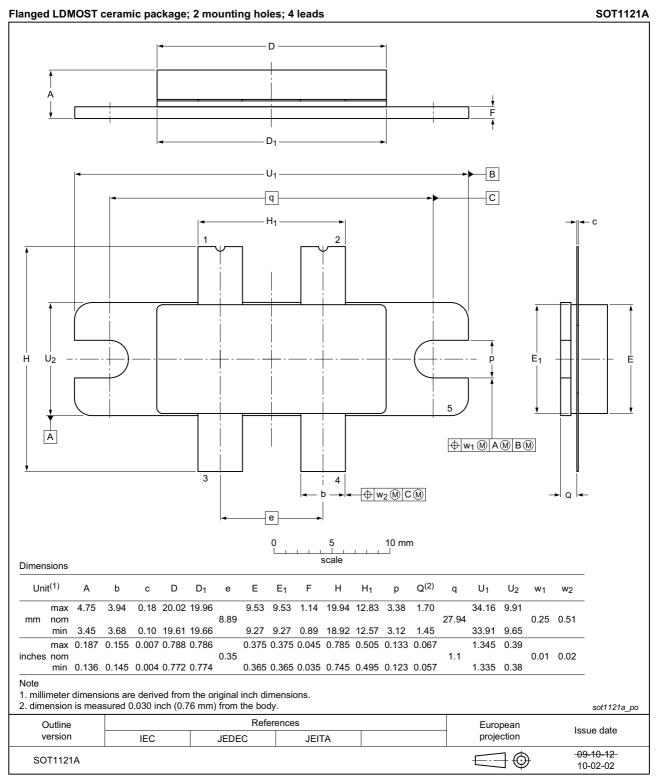
I <sub>AS</sub>	E <sub>AS</sub>
(A)	(J)
<tbd></tbd>	<tbd></tbd>
<tbd></tbd>	<tbd></tbd>
<tbd></tbd>	<tbd></tbd>

For information see application note AN10273.

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## 8. Package outline



#### Fig 3. Package outline SOT1121A

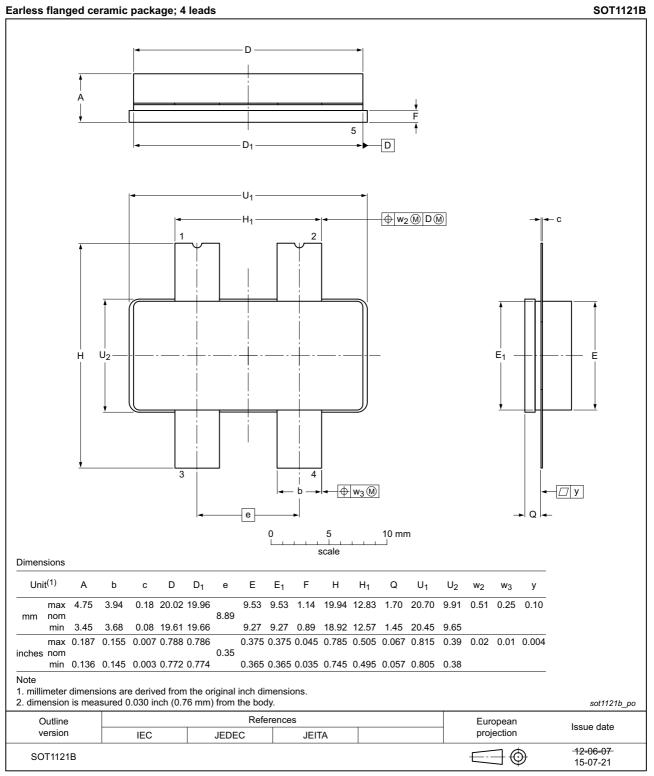
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#### Fig 4. Package outline SOT1121B

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## 9. Handling information

### CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

## **10. Abbreviations**

Table 11. Ab	Table 11. Abbreviations			
Acronym	Description			
CW	Continuous Wave			
ESD	ElectroStatic Discharge			
HF High Frequency				
LDMOS	Laterally Diffused Metal-Oxide Semiconductor			
LDMOST	Laterally Diffused Metal-Oxide Semiconductor Transistor			
MTF	Median Time to Failure			
SMD	Surface Mounted Device			
UIS	Unclamped Inductive Switching			
VSWR	Voltage Standing-Wave Ratio			

### 11. Revision history

#### Table 12.Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLF182XR_BLF182XRS#2	20150901	Objective data sheet	-	BLF182XR_BLF182XRS v.1
Modifications:	• The format of this document has been redesigned to comply with the new identity guidelines of Ampleon.			
	<ul> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>			
BLF182XR_BLF182XRS v.1	20150723	Objective data sheet	-	-

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Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[0] The medicate tetra of device (a) developed in this device of the second sec

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